

Lead (Pb) Free Product - RoHS Compliant

L660N-06

For Plant Growth and Photo Synthetically Active Radiation use

L660N-06 is an AlGaInP LED mounted on a lead frame with a clear epoxy lens.

This is designed for the highest Po and dampproof.

On forward bias it emits a band of visible light, which peaks 660nm.

◆ Specifications

1) Product Name Red LED Lamp 2) Type No. L660N-06

3) Chip

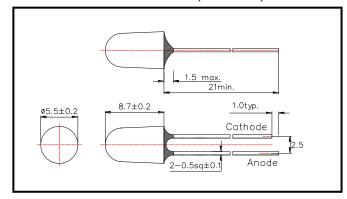
(1) Chip Material AlGaInP(2) Peak Wavelength 660nm typ.

4) Package

(1) Type Φ 5mm clear molding

(2) Resin Material Epoxy Resin(3) Lead Frame Soldered

♦ Outer dimension (Unit: mm)



♦ Absolute Maximum Ratings

Item	Symbol	Maximum Rated Value Unit		Ambient Temperature	
Power Dissipation	Po	120	mW	Ta=25°C	
Forward Current	lF	50	mΑ	Ta=25°C	
Reverse Voltage	Vr	5	V	Ta=25°C	
Junction Temperature	TJ	100	°C		
Thermal Resistance	Rthjp	190	K/W		
Operating Temperature	Topr	-40 ~ +80	°C		
Storage Temperature	Тѕтс	-40 ~ +100	°C		
Soldering Temperature	Tsol	265	°C		

[‡]Pulse Forward Current condition: Duty=1% and Pulse Width=10us.

◆ Electro-Optical Characteristics

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	VF	IF=20mA		2.10	2.3	V
Reverse Current	lr	Vr=5V			10	uA
Total Radiated Power	Po	IF=20mA	10	15		mW
Radiant Intensity	ΙE	Ir=50mA		120		mW/sr
Brightness	Ιν	Ir=20mA		13,000		mcd
Peak Wavelength	λР	Ir=20mA	650	660	670	nm
Half Width	Δλ	IF=20mA		18		nm
Viewing Half Angle	θ 1/2	Ir=20mA		±3		deg.

[#]Brightness is measured by Tektronix J-16.

[‡]Soldering condition: Soldering condition must be completed within 3 seconds at 265°C

[‡]Thermal resistance: junction - ambient, leads 7mm, soldered on PCB

[‡]Total Radiated Power is measured by Photodyne #500